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March 2015



FGH75N60UF 600 V, 75 A Field Stop IGBT

Features

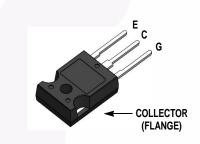
- High Current Capability
- Low Saturation Voltage: $V_{CE(sat)} = 1.9 \text{ V} @ I_C = 75 \text{ A}$
- High Input Impedance
- Fast Switching
- RoHS Compliant

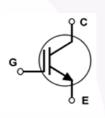
Applications

• Solar Inverter, UPS, Welder, PFC

General Description

Using novel field stop IGBT technology, Fairchild's field stop IGBTs offer the optimum performance for solar inverter, UPS, welder and PFC applications where low conduction and switching losses are essential.





Absolute Maximum Ratings

Symbol	Description		Ratings	Unit
V _{CES}	Collector to Emitter Voltage	600	V	
V _{GES}	Gate to Emitter Voltage		±20	V
	Transient Gate-to-Emitter Voltage		±30	v
I _C	Collector Current	@ T _C = 25°C	150	A
·C	Collector Current	@ T _C = 100 ^o C	75	A
I _{CM (1)}	Pulsed Collector Current	@ T _C = 25°C	225	A
P _D	Maximum Power Dissipation $@T_{C} = 25^{\circ}C$		452	W
. D	Maximum Power Dissipation $@ T_C = 100^{\circ}C$		181	W
Tj	Operating Junction Temperature		-55 to +150	°C
T _{stg}	Storage Temperature Range		-55 to +150	°C
TL	Maximum Lead Temp. for soldering Purposes, 1/8" from case for 5 seco		300	°C

Notes:

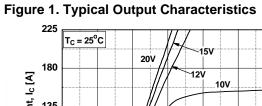
1: Repetitive rating: Pulse width limited by max. junction temperature

Thermal Characteristics

Symbol	Symbol Parameter		Max.	Unit	
$R_{\theta JC}$ (IGBT)	Thermal Resistance, Junction to Case	-	0.276	°C/W	
R_{\thetaJA}	Thermal Resistance, Junction to Ambient	-	40	°C/W	

Part Number		oer Top Mark	Package	Packing Method	Reel Size	Tape Wi	dth Q	Quantity	
FGH75N60	FGH75N60UFTU FGH75N60UF TO-247		Tube	N/A	N/A		30		
Electric	al Ch	aracteristics	s of the IC	GBT $T_{C} = 25^{\circ}C$ unless other	wise noted				
Symbol		Paramete	r	Test Condition	ns Mi	n. Typ.	Max.	Unit	
Off Charac	teristics					I	4		
BV _{CES}	T	or to Emitter Break	down Voltage	V _{GE} = 0 V, I _C = 250 μA	60	0 -	-	V	
$\Delta BV_{CES} / \Delta T_J$		ature Coefficient o	-	$V_{GE} = 0 V, I_C = 250 \mu A$	-	0.75	_	V/°C	
	Collector Cut-Off Current		V _{CE} = V _{CES} , V _{GE} = 0 V	_		250	μA		
				$V_{CE} = V_{CES}, V_{GE} = 0 V$ $V_{GE} = V_{GES}, V_{CE} = 0 V$			±400	nA	
I _{GES}		G-E Leakage Current		*GE = *GES; *CE = 0 V			100	11/4	
On Charac	teristics								
V _{GE(th)}	G-E Th	reshold Voltage		$I_C = 250 \ \mu\text{A}, \ V_{CE} = V_{GE}$	4.0	5.0	6.5	V	
				I _C = 75 A, V _{GE} = 15 V		1.9	2.4	V	
V _{CE(sat)}	Collecto	Collector to Emitter Saturation Voltage		$I_{C} = 75 \text{ A}, V_{GE} = 15 \text{ V},$ $T_{C} = 125^{\circ}\text{C}$	-	2.15	-	V	
					I		1		
Dynamic C	1				1				
C _{ies}	-	apacitance		V 20 V V 0 V	-	3850	-	pF	
C _{oes}	-	out Capacitance		V _{CE} = 30 V _, V _{GE} = 0 V, f = 1 MHz	-	375	-	pF	
C _{res}	Revers	e Transfer Capacit	ance		-	147	-	pF	
Switching	Charact	eristics							
t _{d(on)}	1	n Delay Time			-	27	-	ns	
t _r	Rise Ti				-	70	-	ns	
t _{d(off)}		ff Delay Time		V _{CC} = 400 V, I _C = 75 A,	-	128	-	ns	
t _f	Fall Tin			$R_{G} = 3 \Omega, V_{GE} = 15 V,$	-	30	80	ns	
E _{on}		n Switching Loss		Inductive Load, $T_C = 25^{\circ}$	°C -	3.05	-	mJ	
E _{off}		ff Switching Loss		-	-	1.35	-	mJ	
E _{ts}		witching Loss		-	-	4.4	_	mJ	
t _{d(on)}		n Delay Time				27	-	ns	
t _r	Rise Ti			-	-	74	-	ns	
t _{d(off)}		ff Delay Time		V _{CC} = 400 V, I _C = 75 A,	-	153	-	ns	
t _f	Fall Tim		R _G = 3 Ω, V _{GE} = 15 V,		-	35	-	ns	
E _{on}		n Switching Loss		Inductive Load, T _C = 125	5°C -	3.6		mJ	
E _{off}		ff Switching Loss			-	1.8		mJ	
E _{ts}		witching Loss			-	5.4	-	mJ	
Q _g		ate Charge			-	250	-	nC	
Q _{ge}		Emitter Charge		$V_{CE} = 400 \text{ V}, I_{C} = 75 \text{ A},$		30	-	nC	
	1			V _{GE} = 15 V	1	1	1	1	

Typical Performance Characteristics





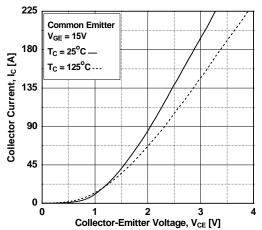


Figure 5. Saturation Voltage vs. Case Temperature at Variant Current Level

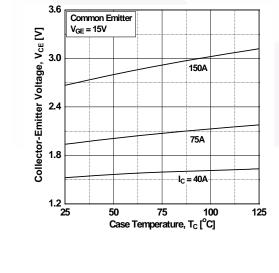


Figure 2. Typical Output Characteristics

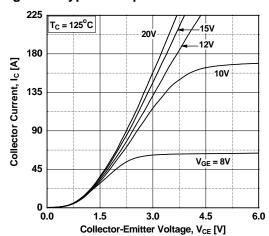


Figure 4. Transfer Characteristics

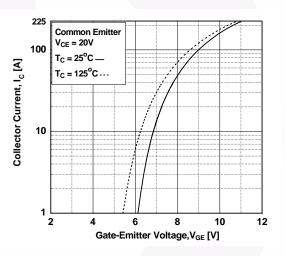


Figure 6. Saturation Voltage vs. V_{GE}

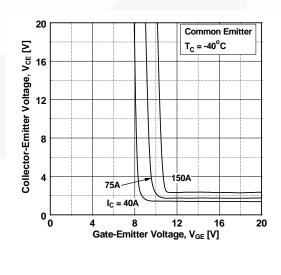


Figure 7. Saturation Voltage vs. V_{GE} 20 Common Emitter $T_{\rm C} = 25^{\circ}C$ Collector-Emitter Voltage, V_{CE} [V] 16 12 8 150A 4 75A $I_{\rm C} = 40$ A 0 L 8 12 20 16 4 Gate-Emitter Voltage, V_{GE} [V] **Figure 9. Capacitance Characteristics** 8000 Common Emitter V_{GE} = 0V, f = 1MHz $T_C = 25^{\circ}C$ 6000 Cies Capacitance [pF] 4000 C_{oes} 2000 C, 0 10 1 30 Collector-Emitter Voltage, V_{CE} [V] Figure 11. SOA Characteristics 500 .10µs 100 Collector Current, I_c [A] 100µs 10 1ms 10 ms 1 DC Single Nonrepetitive

Typical Performance Characteristics

Figure 8. Saturation Voltage vs. V_{GE}

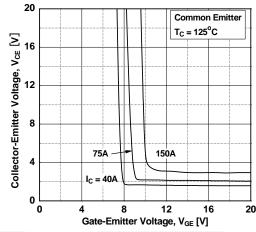
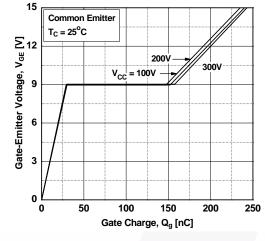
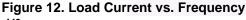
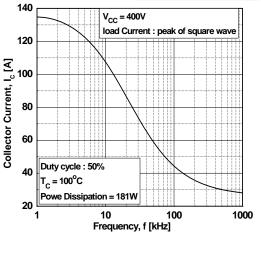


Figure 10. Gate charge Characteristics







Pulse T_C = 25^oC

Curves must be derated

10

100

Collector-Emitter Voltage, V_{CE} [V]

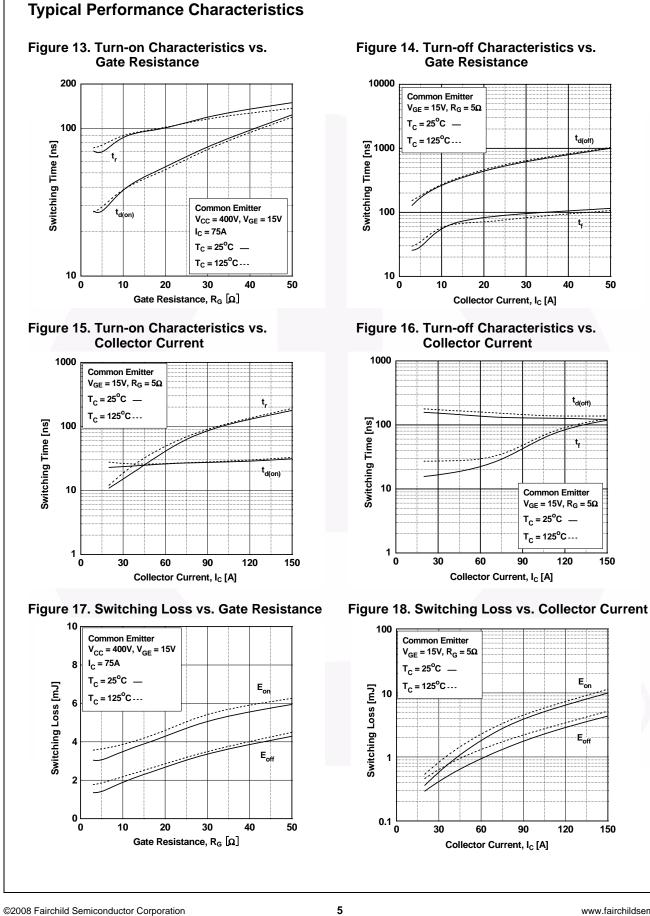
linearly with increase in temperature

0.1

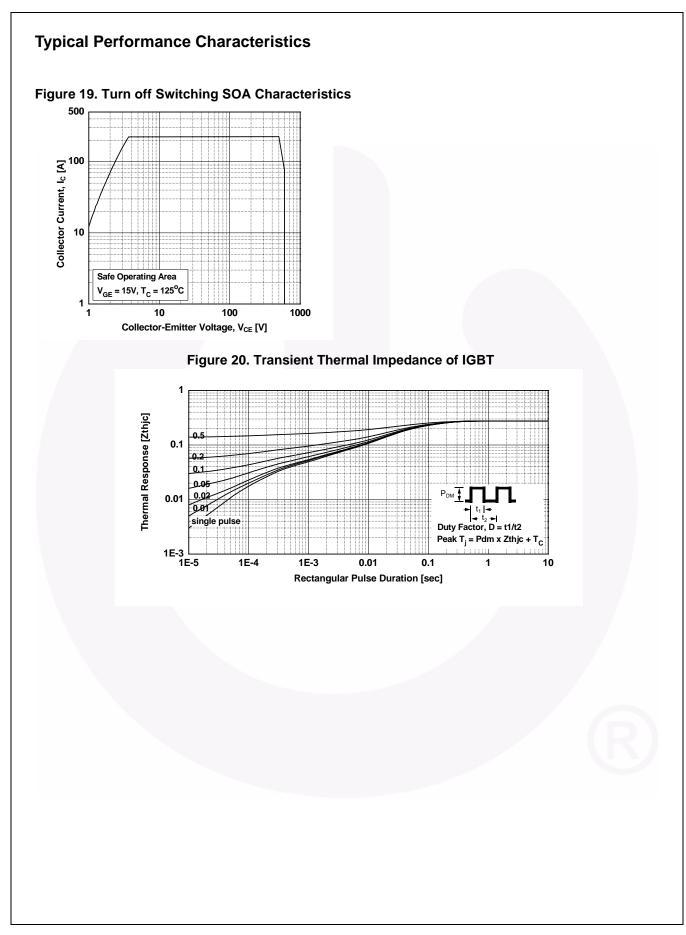
0.01

1

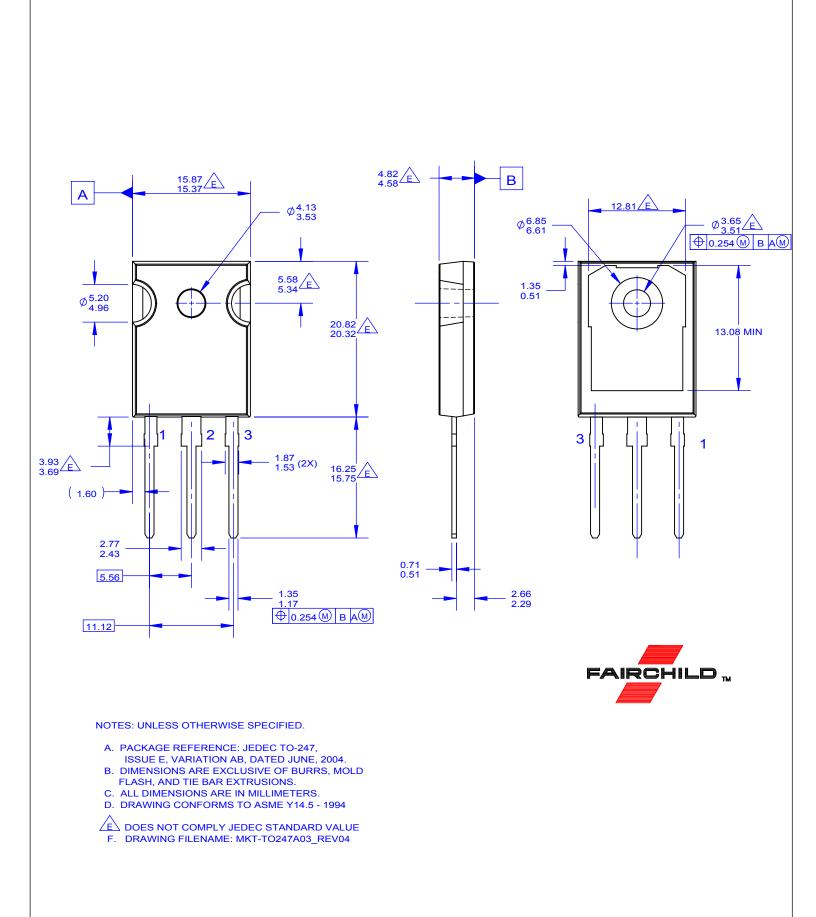
1000



FGH75N60UF Rev. 1.5



FGH75N60UF — 600 V, 75 A Field Stop IGBT



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